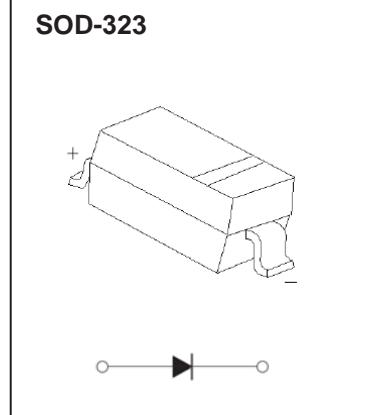


## FEATURES

For use in low voltage, high frequency inverters  
Free wheeling, and polarity protection applications.

**MARKING:** B5817WS: SJ  
B5818WS:SK  
B5819WS: SL



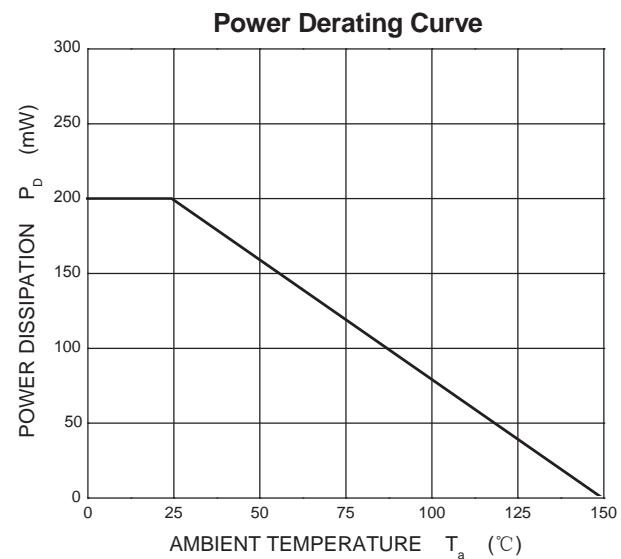
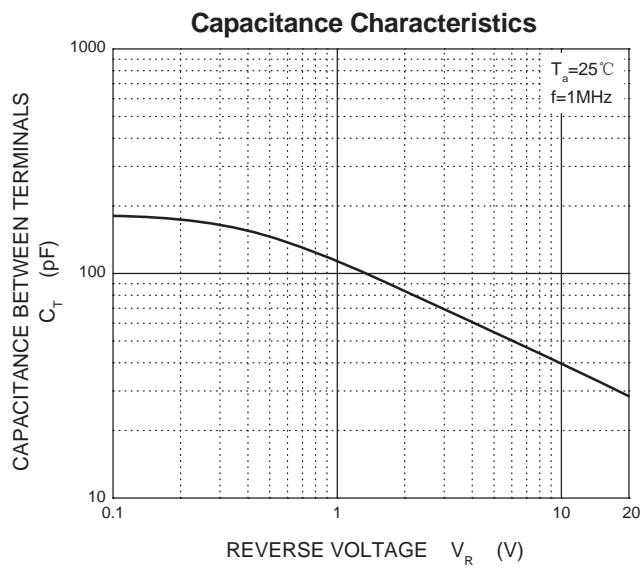
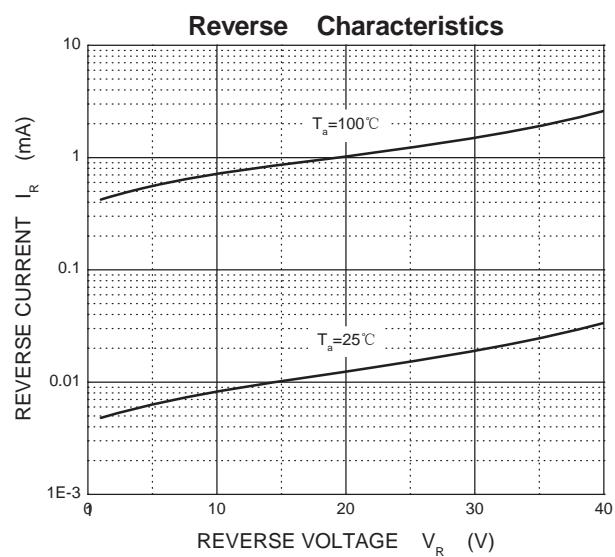
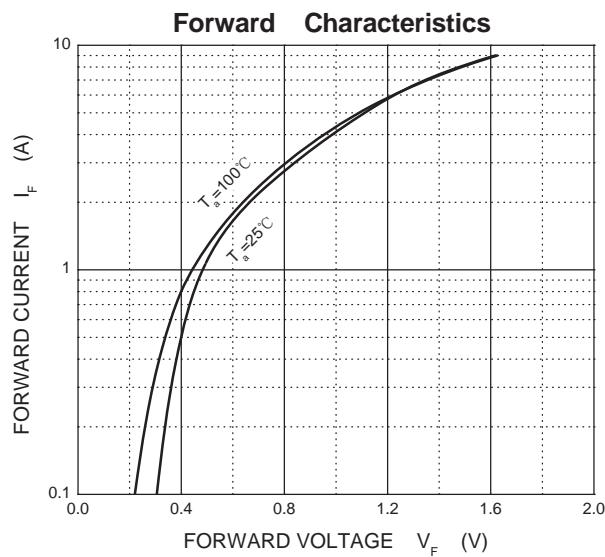
## Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	B5817WS	B5818WS	B5819WS	Unit
Non-Repetitive Peak Reverse Voltage	V <sub>RM</sub>	20	30	40	V
Peak Repetitive Peak Reverse Voltage	V <sub>RRM</sub>				
Working Peak Reverse Voltage	V <sub>RWM</sub>	20	30	40	V
DC Blocking Voltage	V <sub>R</sub>				
RMS Reverse Voltage	V <sub>R(RMS)</sub>	14	21	28	V
Average Rectified Output Current	I <sub>O</sub>		1		A
Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>		25		A
Repetitive Peak Forward Current	I <sub>FRM</sub>		1.5		A
Power Dissipation	P <sub>d</sub>		200		mW
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>		625		°C/W
Storage Temperature	T <sub>STG</sub>		-55~+150		°C

## ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	V <sub>(BR)</sub>	I <sub>R</sub> = 1mA B5817WS B5818WS B5819WS	20 30 40		V
Reverse voltage leakage current	I <sub>R</sub>	V <sub>R</sub> =20V V <sub>R</sub> =30V V <sub>R</sub> =40V B5817WS B5818WS B5819WS		1	mA
Forward voltage	V <sub>F</sub>	B5817WS I <sub>F</sub> =1A I <sub>F</sub> =3A B5818WS I <sub>F</sub> =1A I <sub>F</sub> =3A B5819WS I <sub>F</sub> =1A I <sub>F</sub> =3A		0.45 0.75 0.55 0.875 0.6 0.9	V
Diode capacitance	C <sub>D</sub>	V <sub>R</sub> =4V, f=1MHz		120	pF

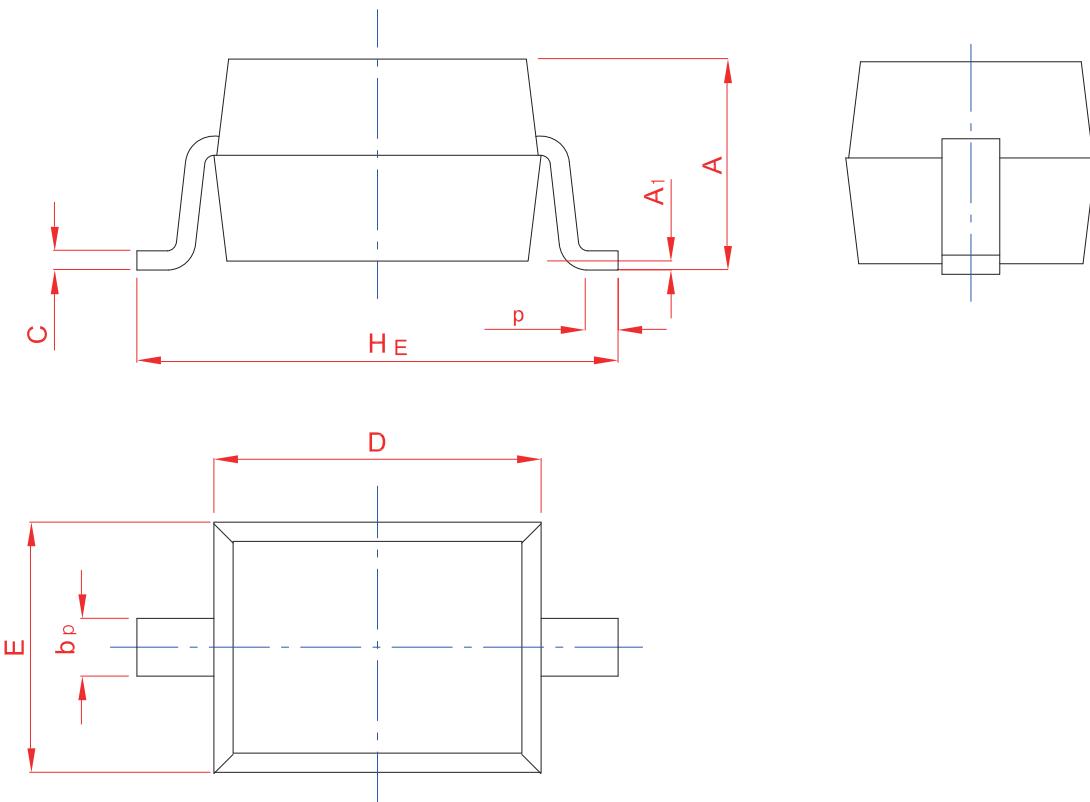
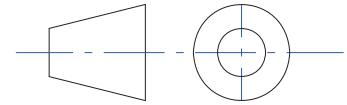
## Typical Characteristics



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	$b_p$	C	D	E	$H_E$	$A_1$	$L_p$
mm	1.20 0.90	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30	0.10 0.01	0.50 0.20